Comparison of photocatalytic and transport properties of TiO$_2$ and ZnO nanostructures for solar-driven water splitting†

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Titanium dioxide (TiO$_2$) and zinc oxide (ZnO) nanostructures have been widely used as photocatalysts due to their low-cost, high surface area, robustness, abundance, and non-toxicity. In this work, four TiO$_2$ and ZnO-based nanostructures, i.e. TiO$_2$ nanoparticles (TiO$_2$ NPs), TiO$_2$ nanotubes (TiO$_2$ NTs), ZnO nanowires (ZnO NWs) and ZnO@TiO$_2$ core–shell structures, specifically prepared with a fixed thickness of about 1.5 μm, are compared for the solar-driven water splitting reaction, under AM1.5G simulated sunlight. Complete characterization of these photo-electrodes in their structural and photo-electrochemical properties was carried out. Both TiO$_2$ NPs and NTs showed photo-current saturation reaching 0.02 and 0.12 mA cm$^{-2}$, respectively, for potential values of about 0.3 and 0.6 V vs. RHE. In contrast, the ZnO NWs and the ZnO@TiO$_2$ core–shell samples evidence a linear increase of the photocurrent with the applied potential, reaching 0.45 and 0.63 mA cm$^{-2}$ at 1.7 V vs. RHE, respectively. However, under concentrated light conditions, the TiO$_2$ NTs demonstrate a higher increase of the performance with respect to the ZnO@TiO$_2$ core–shells. Such material-dependent behaviours are discussed in relation with the different charge transport mechanisms and interfacial reaction kinetics, which were investigated through electrochemical impedance spectroscopy. The role of key parameters such as electronic properties, specific surface area and photo-catalytic activity in the performance of these materials is discussed. Moreover, proper optimization strategies are analysed in view of increasing the efficiency of the best performing TiO$_2$ and ZnO-based nanostructures, toward their practical application in a solar water splitting device.

1. Introduction

With increasing concern over the fossil fuel depletion and the environmental degradation, energy is one of the greatest issues that humanity will be facing in the coming years. Hydrogen, present in the water molecules, is an efficient energy carrier and is also environmentally friendly: therefore using solar energy to split water into oxygen and hydrogen (also called “artificial photosynthesis”) is a key point towards the development of sustainable and renewable energy devices.

More than 40 years after the pioneering work of Fujishima and Honda,1 the search for suitable semiconductors to be employed for the water dissociation into molecular hydrogen and oxygen is still an open challenge. It has been found2 that the photochemical water-splitting reaction can be catalyzed by over 140 metal oxides, perovskites and oxynitrides, and the principal controlling factors of the photocatalysis activity have been identified. Nevertheless, many questions concerning the molecular mechanisms of water reduction and oxidation and the charge transfer dependence on the electronic and structural properties have not been completely solved yet, and the ideal semiconducting photocatalyst has still to be identified. At the same time, research efforts focused on proposing artificial photosynthesis devices have been recently greatly increased in number and importance, but functional prototypes with convenient efficiencies have still to be fabricated.3

The H$_2$ photocatalytic generation involves three main steps: (i) absorption of photons (with energy higher than the semiconductor band gap ($E_g$) and consequent generation of electron–hole (e$^-$–h$^+$) pairs in the semiconductor), (ii) excited charge carrier separation and migration within the semiconductor, and (iii) surface reaction of the carriers with water molecules. To provide the water splitting, the bottom of the semiconductor conduction band must be in a more negative energy position with respect to
the reduction potential of water to produce H₂; and the top of the valence band must be more positive than the oxidation potential of water to produce O₂. Furthermore, the photo-catalyst must be stable in aqueous solutions under photo-irradiation. The total amount of generated H₂ molecules is determined by the amount of excited electrons at the water/photo-catalyst interface capable of reducing water. Charge recombination and separation—migration processes are the two most important competitive processes that largely affect the efficiency of the photocatalytic reaction. Charge recombination reduces the number of e⁻−h⁺ pairs by emitting light or generating phonons. Efficient charge separation, fast charge carrier transport and limited bulk/surface charge recombination are thus fundamental characteristics of an optimal semiconductor photocatalyst material.

Since 1972, titanium dioxide (TiO₂) has been the most commonly studied material for photocatalysis. It exhibits an appropriate band gap of about 3.2 eV, together with high photocatalytic efficiency, good chemical and optical stability, optimal environmental and biological compatibility. Zinc oxide (ZnO) has also been largely considered because of its band gap energy, which is comparable to TiO₂, with the energy levels located almost at the same positions, its higher electron mobility and lifetime, relatively lower production costs and easy fabrication under a variety of nanostructures such as nanowires, nanoribbons, nanobelts, nanocombs, nanospheres, nanofibers, and nanotetrapods. To date TiO₂ and ZnO have been close to be ideal photocatalysts. They are relatively inexpensive and they provide photo-generated holes with high oxidizing power due to their wide band gap energy. Unfortunately their solar-to-hydrogen efficiency is limited by the high band gap and the many electron–hole recombination centers; moreover, ZnO has the disadvantage of a facile dissolution under UV light irradiation in aqueous solutions.

Different routes have been adopted for enhancing the TiO₂ and ZnO photocatalytic performances. Based on the fact that size, shape and also defects significantly affect the final photocatalytic activity, the optimization of the morphology and the crystalline structure has been studied, and a large variety of micro and nanostructures has been suggested. In particular, one-dimensional nanostructures such as nanorods, nanotubes and nanowires have emerged as a very promising alternative to nanoparticle-based architectures: the cylindrical and/or tubular configuration is very convenient to increase the surface area without affecting the total geometric surface and the unidirectional electric channel should allow a better charge transport. Moreover, many strategies to change the chemical composition and surface properties of the semiconductor have been tried, for instance by ion implantation, doping, dye sensitization or hydrogenation, and also hybrid nanostructures, such as core–shell nanocomposites, have been proposed, which consist of an inner nanostructure encapsulated inside an outer shell of a different material.

In particular, our group has recently developed different easy and low-cost procedures for the synthesis of TiO₂ and ZnO-based nanostructures. In particular, TiO₂ anatase nanoparticles (TiO₂ NPs) leading to mesoporous films have been prepared through an innovative sol–gel method on Fluorinated Tin Oxide (FTO)-covered glasses. Self-organized TiO₂ nanotubes (TiO₂ NTs) have been grown by anodic oxidation on Ti foils, while ZnO nanowires (ZnO NWs) have been obtained on a FTO seeded substrate using a hydrothermal route. Finally, ZnO@TiO₂ core–shell structures have been fabricated on FTO by covering the ZnO NWs with sol–gel synthesized TiO₂ nanoparticles. In particular, the TiO₂ nanoparticle-based films, the ZnO nanowires and the ZnO@TiO₂ core–shell structures have already demonstrated promising photocatalytic properties for the water splitting reaction. The ZnO@TiO₂ core–shell heterostructures offer some advantages: the TiO₂ shell functions as a protective layer to reduce the ZnO degradation and the multi-dimensional contact permits to fully utilize the heterojunction between the two semiconductors, which exhibits very favorable electron-transfer properties that are beneficial to an effective separation of the photo-generated e⁻−h⁺ pairs. For what concerns the TiO₂ NTs fabricated in our laboratory, they are employed for the first time in this work for the solar water splitting reaction.

In general, due to the broad range of dimensions and thicknesses of fabricated TiO₂ and ZnO nanostructures, and because of the different testing operative conditions, a direct comparison of both transport properties and performance of photoactive electrodes, between our materials and those reported in the literature, is not straightforward. Thus, in this paper, the aim is to compare the transport and photo-catalytic properties of four different photoelectrodes based on TiO₂ and ZnO nanostructures, specifically prepared in order to have the same thickness and the same active area. The studied electrodes are based on (i) mesoporous films of TiO₂ NPs, (ii) TiO₂ NTs, (iii) ZnO NWs and (iv) 1D ZnO@TiO₂ core–shell nanostructures. The thickness of the four photocatalysts has been fixed at about 1.5 μm and the active area to about 4 cm², in order to reliably compare the electronic and PEC properties of these materials under the same operative conditions, for the sunlight-activated water splitting reaction. The morphological and optical properties of these nanostructures are also presented and discussed.

The electrochemical impedance spectroscopy (EIS) has been chosen as the main characterization technique to investigate the different charge transport mechanisms and interfacial kinetics. The role of key parameters such as electronic properties, specific surface area and photo-catalytic activity in the performance of these nanostructures is finally analyzed. Insights into different optimization strategies that can open up the way to increase the effectiveness of each of the studied materials are summarized, in view of their practical application in a solar water splitting device.

2. Experimental

2.1. Synthesis of the nanostructures

2.1.1. TiO₂ nanoparticle film fabrication by sol–gel synthesis.

Titanium(IV) isopropoxide (TTIP, 97%), glacial acetic acid (AcOH, 99.7%) and the surfactant Tween 20, all from Sigma Aldrich were used as purchased. Firstly, TTIP was hydrolyzed in glacial AcOH and then the Tween 20 was added under vigorous stirring. The mixture was added dropwise to the deionized...
water and the final solution was aged under continuous stirring for 48 h at ambient temperature. TTIP, glacial AcOH, Twee200 and water were at fixed molar ratios 1:10:1:300. The obtained solution was treated in a rotary evaporator at 40 °C for 2 h under vacuum conditions. The final solution containing the TiO2 nanoparticles, homogeneous and stable for weeks, has then been used for the preparation of the TiO2 NPs film. The sol was deposited onto FTO-coated glass (7 Ω sq-1 from Solaronix) in an exposed area of 2 cm × 2 cm by the spin-coating technique using a two-step deposition program: (1) 500 rpm for 10 s followed by (2) 3000 rpm for 10 s. The deposited film was dried at 360 °C for 30 min before spin-coating every successive layer. A total of three deposited layers were reached. Finally, the film was annealed at 500 °C in air at a heating rate of 1 °C min-1, followed by natural cooling to room temperature. Further details of the synthesis and characterization of these films are described in our previous paper.14

2.1.2. TiO2 nanotube array fabrication by anodic oxidation.

TiO2 nanotube arrays were grown by a quick anodic oxidation of Ti foil (250 μm thick, 99.6%-purity, Goodfellow) in an electrolytic solution made of 0.5 wt% NH4F (98%, Sigma Aldrich) and 2.5 wt% deionized water in ethylene glycol (99.5%, Sigma Aldrich). The Ti foils were manually cut into 2 cm × 4 cm pieces and carefully cleaned by ultra-sonication in acetone and subsequently in ethanol. A rapid etching in a HF (1 wt%) aqueous solution was performed in order to remove the native oxide on the commercial Ti foil and to obtain a fresh surface for NT growth. Afterwards the samples were masked with a polyimide-based tape (exposed area 2 cm × 2 cm) and used as an anode in a two-electrode electrochemical cell (a platinum foil was used as a counter electrode) under continuous stirring and under ambient conditions. Anodization was performed applying a 60 V potential for 5 min in order to obtain a NT carpet with thickness ranging between 1.5 and 1.9 μm. Finally, the TiO2 NTs were annealed at 450 °C (30 min heating ramp, 30 min in temperature, cooling down in 2 h) to crystallize them into the anatase phase. More details of the process are given elsewhere.15,16

2.1.3. ZnO nanowires grown by hydrothermal synthesis.

ZnO nanowires were obtained using a hydrothermal route with a conventional approach17 using two steps: first the preparation of a ZnO seed-layer on the FTO glass substrates (with an exposed area of 2 cm × 2 cm), and second the NW growth. Briefly, the seeded substrates were obtained by dip coating (speed 375 mm min-1) the FTO-covered glass in a 10 mM solution of zinc acetate (Sigma, purity 98%) in ethanol and then calcining them in air at 350 °C for 1 h (heating rate 5 °C min-1). Afterwards, the ZnO NWs were grown by immersing the seeded substrates in a 100 mL water solution of zinc nitrate hexahydrate (Zn(NO3)2.6H2O, 25 mM, 98%, Sigma-Aldrich), hexamethylene-teramine (HMT, 12.5 mM, Sigma-Aldrich), polyethyleneimine (PEI, 5 mM, average Mw ≈ 800, Sigma-Aldrich) and ammonium hydroxide (NH2OH, 28%, 320 mM, Sigma-Aldrich) for 2 h at 88 °C under stirring (300 rpm). The obtained ZnO NWs were then thermally treated in air at 500 °C for 1 h (heating rate 1 °C min-1).

2.1.4. ZnO@TiO2 core–shell heterostructures prepared by sol–gel impregnation. The ZnO@TiO2 core–shell structures were obtained as previously reported18,19 by immersing for 10 min the ZnO NWs grown on FTO glass substrates in a non-acid titania precursor solution constituted by 0.46 M titanium isopropoxide (TTIP, 97%, Sigma-Aldrich), 0.28 M acetylacetone (99%, Fisher Aldrich) and 0.92 M bi-distilled water (from a Direct-Q, Millipore system) in 5 mL of 1-butanol (anhydrous, 99.8%, Sigma-Aldrich) under stirring at room temperature. The sample was then dried in the horizontal position and thermally treated in air at 450 °C for 30 min (heating rate 1 °C min-1) for the complete titania crystallization into the anatase phase.

2.2. Morphological and optical characterization

The morphology and the structural properties of the different nanostructures were investigated by means of Field Emission Scanning Electron Microscopy (FESEM) using either a ZEISS Auriga or a ZEISS Merlin, and by means of a FEI TECNAI F20ST Transmission Electron microscope (TEM) operating in Bright-Field (BF) and Scanning Transmission Electron Microscopy (STEM) modes. The instrument was also equipped with a High-Angle Annular Dark Field (HAADF) detector. The samples for TEM/STEM characterization were prepared by detaching the nanostructures from the substrate, dispersing them in ethanol employing an ultrasonic bath, and putting a drop of the dispersion on the top of a holey carbon copper grid. The mean geometrical sizes of the different nanostructures, obtained from FESEM images, have also been used to calculate the mean exposed surface area (SA). The UV-visible spectra were recorded on a Cary 5000 Scan UV-visible spectrophotometer, using a diffuse reflectance integrating sphere. All spectra were recorded in both Kubelka–Munk function F(R) and total reflectance (%R) modes, and background subtracted.

2.3. Photo-electrochemical characterization

The PEC experiments were performed in a Teflon reactor equipped with a quartz window for frontal illumination. All the tests were carried out in a three electrode configuration using the TiO2 NP film, TiO2 NTs, ZnO NWs or ZnO@TiO2 core–shell heterostructures as the working electrodes for the water photo-electrolysis reaction, a platinum wire as the counter electrode, and an Ag/AgCl (KCl 3 M) as the reference electrode, in a 0.1 M NaOH aqueous electrolyte (pH = 12.7). N2 was bubbled through the electrolyte solution for 30 min before the tests. The photoelectrochemical measurements were performed using a multi-channel VSP potentiostat/galvanostat (by BioLogic), with EC-Lab® software (version 10.1×) for data acquisition. The current-voltage (I-V) characteristic curves were recorded by means of Linear Sweep Voltammetry (LSV) at a scan rate of 10 mV s-1, when a constant open circuit voltage was achieved, varying the applied potential from −0.9 V to 0.8 V vs. Ag/AgCl, in the dark and under AM1.5G simulated sunlight (using a 450 W Xe lamp by Newport with an AM1.5G filter and a water filter model 6123NS) using a power density of 100 mW cm-2 (including 3.7 mW cm-2 in the UV range: 280 to 400 nm). The irradiance was measured by means of a Delta Ohm Photo-radiometer model HD2102.1.
Chrono-amperometric ($I$–$t$) tests were carried out to examine the photo-response of the nanostructures over time at −0.1 V and 0.3 V vs. Ag/AgCl (0.86 and 1.26 V_RHE) under continuous ON–OFF light cycles, with the same illumination condition used for the LSV. Further LSV was recorded with the TiO$_2$ NTs and the ZnO@TiO$_2$ core–shells with a higher light intensity than in the previous tests, using 220 mW cm$^{-2}$ (having an UV contribution of 14 mW cm$^{-2}$). The measured potentials versus the Ag/AgCl reference electrode were converted to the reversible hydrogen electrode (RHE) scale via the Nernst eqn (1):

$$E_{\text{RHE}} = E_{\text{Ag/AgCl}} + 0.059 \cdot \text{pH} + E'_{\text{Ag/AgCl}}$$  

(1)

where $E_{\text{RHE}}$ is the converted potential vs. RHE in V vs. RHE (V_RHE), $E_{\text{Ag/AgCl}}$ is the experimental potential measured against the Ag/AgCl reference electrode in V vs. Ag/AgCl (V_{Ag/AgCl}), and $E'_{\text{Ag/AgCl}}$ is the standard potential of Ag/AgCl (KCl 3 M) at 25 °C (i.e. 0.21 V). EIS curves were recorded using the same potentiostat described above, from 0.1 Hz to 100 kHz, with an AC amplitude of 25 mV, at different applied potentials from −0.5 to 0.5 V vs. Ag/AgCl, in the dark and under AM1.5G simulated solar light (100 mW cm$^{-2}$). EIS for Mott–Schottky plots was performed at a frequency of 5 kHz, with an AC amplitude of 20 mV, from −0.8 to 0.7 V vs. Ag/AgCl with a scan step of 0.1 V.

### 3. Results and discussion

#### 3.1. Morphology and structure

The morphology and the crystalline structure of the TiO$_2$- and ZnO-based nanostructures here studied have already been described elsewhere. Nonetheless, 45° tilted FESEM views of the TiO$_2$ NPs and of the different vertically aligned nanostructures prepared for the present work are reported in Fig. 1. All the four considered nanostructures have a comparable thickness of about 1.5 μm. Fig. 1a shows the TiO$_2$ NP film, which is uniform and continuous, characterized by nanoparicles with a size ranging between 7 and 13 nm, interconnected in a mesoporous network. As shown in Fig. 1b, the TiO$_2$ NTs grown by anodic oxidation are vertically arranged with respect to the Ti foil. The TiO$_2$ NTs are closely packed, with an outer diameter (o.d.) in the range 100–130 nm and inner diameter (i.d.) around 70 nm. The ZnO NWs, shown in Fig. 1c, are almost vertically aligned, with a diameter ranging between 100 and 200 nm. Finally, Fig. 1d put in evidence the good coverage of the ZnO NWs with the titania shell made of crystalline anatase nanoparticles. The different nanostructures have also been investigated with the TEM technique, both in BF-TEM and in STEM modes, as shown in Fig. 2. In Fig. 2a, two BF-TEM images at different magnification show the TiO$_2$ nanoparticles in the anatase crystalline form, as put in evidence by the selected area electron diffraction (SAED) analysis (not reported here) and by the Fast Fourier Transform (FFT) in the inset. The size of the particles is in the range 10–20 nm, in agreement with the previously reported FESEM characterization. In Fig. 2b, the BF-TEM characterization of the TiO$_2$ NTs is reported with different magnifications. The lower magnification put in evidence the shape of the TiO$_2$ NTs, where the wall, with a thickness of about 25 nm, is clearly visible. The high-magnification images collected in two distinct regions of the NTs confirm the polycrystallinity of the TiO$_2$ NTs, which are constituted by the anatase phase.

#### 3.2. Optical properties

The UV-Vis spectra of the four studied TiO$_2$ and ZnO nanostructures, in Kubelka–Munk function $F(R)$ and total reflectance ($R$) modes are reported in Fig. 3a and b. As is well known, $F(R)$ is directly proportional to the absorbance. In the range from 200 to 400 nm, F(R) is higher for the bare ZnO NWs than for the ZnO@TiO$_2$ core–shell sample and even for the pure titania nanomaterials, i.e. TiO$_2$ NTs and NPs film. Consistently, the spectra recorded in total reflectance mode (Fig. 3b) of both titania materials (NTs and NPs film) show a strong increase of the light
scattering in the UV range (from 200 to 400 nm), whereas lower scattering is observed for the core–shell sample and is even lower for the bare ZnO NWs. This behavior is attributed to the high degree of crystallinity of the titania-based nanostructures and of the TiO$_2$ shell deposited on the ZnO NWs (consistent with the TEM and X-ray diffraction patterns reported elsewhere\textsuperscript{18,19}), thanks to the thermal treatment at relatively high temperature (see the Experimental section for details). In addition, high scattering levels are expected for rough nanostructures with a high surface area. This is the case of the TiO$_2$ NP film\textsuperscript{14}, the TiO$_2$ NTs\textsuperscript{16} and of the core–shell structure\textsuperscript{19} due to the titania nanoparticles that constitute the shell. The optical band gap values were estimated by using Tauc’s method and are reported in the inset of Fig. 3b. The bare ZnO NWs show a higher $E_g$ value (3.31 eV) than both the core–shell material (3.25 eV) and the nanostructured titania samples, i.e. TiO$_2$ NTs (3.27 eV) and TiO$_2$ NPs film (3.23 eV). The lower band gap values obtained for the core–shell, the TiO$_2$ NTs and TiO$_2$ NPs samples are attributed to the presence of anatase TiO$_2$, whose $E_g$ has been reported to be about 3.2 eV\textsuperscript{4}. Therefore, the narrowing of the $E_g$ in the core–shell nanostructure with respect to the pure ZnO NWs is easily explained.\textsuperscript{18}

### 3.3. Photo-electrochemical activity of the water splitting reaction

The PEC behavior of the TiO$_2$ NPs, TiO$_2$ NTs, ZnO NWs and the ZnO@TiO$_2$ core–shell heterostructures was evaluated using the prepared photoanodes, which have the same active area (4 cm$^2$), for the water photo-electrolysis reaction in 0.1 M NaOH solution (pH = 12.7). Fig. 4a reports the LSV behavior recorded with the four photoanodes. From the LSV scans under dark conditions, from 0.1 to 1.8 V$_{RHE}$, a tiny current in the range of 10$^{-4}$ mA cm$^{-2}$ was obtained for all the nanostructures until reaching the onset potential ($E^*$) for the water oxidation reaction at about 1.75 V$_{RHE}$. As expected, the $E^*$ value is reached at potential higher than the theoretical one ($E^* = 1.23$ V$_{RHE}$), due to the high overpotential effect of TiO$_2$ and ZnO semiconductors. In contrast, during the LSV under simulated sunlight irradiation (AM1.5G, 100 mW cm$^{-2}$), a sudden increase of the photocurrent is observed at potentials more negative than the redox potential $E^*$, because part of the energy required for the oxidation is provided by the light. These results are in agreement with the behavior expected for a n-type semiconductor.\textsuperscript{22}

Under sunlight illumination, the photocurrent density ($J$) of the TiO$_2$ NPs and TiO$_2$ NTs showed an important rise starting at about 0.17 and 0.19 V$_{RHE}$, respectively, reaching a maximum $J$ value of 0.02 and 0.12 mA cm$^{-2}$ at about 0.3 V$_{RHE}$ and 0.6 V$_{RHE}$, respectively, which is associated with the saturation of the TiO$_2$ semiconductor.\textsuperscript{14,23} In contrast, the ZnO NWs showed a pronounced increase of the photocurrent starting at about 0.40 V$_{RHE}$, which continues to rise until reaching a maximum $J$ of 0.45 mA cm$^{-2}$ at 1.7 V$_{RHE}$. The ZnO@TiO$_2$ core–shell electrodes showed similar behavior, but with an enhanced photo-response,
reaching a maximum photocurrent density of 0.63 mA cm\(^{-2}\) at 1.7 V\(_{\text{RHE}}\), a value that is about 1.5 times higher than the one obtained for the ZnO NWs. The larger photocurrents observed with the 1D-nanostructures (TiO\(_2\) NTs, ZnO NWs and ZnO@TiO\(_2\)) with respect to the TiO\(_2\) NPs film (even if they have a similar thickness) could be explained by a more efficient electron injection at the semiconductor–electrolyte interface and a faster electron transport from the photoanode to the substrate, which results in a higher number of collected photoelectrons.\(^{18,19,24}\)

Additionally, it is worth noting that by coupling the ZnO NWs with a shell of TiO\(_2\) NPs a significant increase of the photocurrent density during the water photo-electrolysis reaction is obtained. Indeed, this is related to the absence of a photocurrent saturation region, as occurs with TiO\(_2\) NPs and TiO\(_2\) NTs photoanodes upon illumination.\(^{25}\) Therefore, these results are promising in comparison with other results reported in the literature for the water photo-electrolysis using TiO\(_2\) and ZnO nanostructures.\(^{25,26}\) For instance, a \(J\) value lower than 0.3 mA cm\(^{-2}\) at 1.8 V\(_{\text{RHE}}\) was reported by using nanocoral structures of ZnO\(^{27}\) and N-doped ZnO NWs.\(^{25}\) The photo-activity demonstrated by the ZnO@TiO\(_2\) core–shell sample is also in-line with recent results on pure and N-doped rutile TiO\(_2\) NWs (~1.6 \(\mu\)m).\(^{28}\) Even though, these values are still smaller than those recently
obtained by the coupling of ZnO with visible light absorbing semiconductors, e.g. ZnO-Cds core–shell NWs and ZnO NWs sensitized with CdS/Se quantum dots.

The solar-to-hydrogen efficiency (STHE) of each sample type under sunlight illumination was calculated from the I–V data according to expression:

\[
\text{STHE} = \frac{J(1.23 - E_{\text{RHE}})}{I_{\text{light}}} \times 100 \%
\]

where \(J\) is the photocurrent density (mA cm\(^{-2}\)), \(E_{\text{RHE}}\) is the applied potential (V vs. RHE), and \(I_{\text{light}}\) is the irradiance intensity (i.e., 100 mW cm\(^{-2}\)).

The STHE curves in Fig. 4b show that the maximum of the curves for the four studied samples increases in the following order: TiO\(_2\) NPs, ZnO NWs, TiO\(_2\) NTs and ZnO@TiO\(_2\), according to the following values: 0.013%, 0.047%, 0.071% and 0.073%, respectively. A significant increase of the STHE was obtained using the 1D-nanostructures with respect to TiO\(_2\) NPs, due to their higher photocurrent densities.

It is worth noting that both the TiO\(_2\) NTs and the ZnO@TiO\(_2\) samples gave similar maximum STHE but at different applied potentials, being lower for the NPs (i.e. 0.5 V RHE) than for the core–shell sample (i.e. 0.9 V RHE). This feature could likely be explained by the different photo-catalytic and transport properties of these two materials. In fact, the open circuit voltage (OCV), i.e. the voltage corresponding to \(J = 0\), is an approximated measure of the flat band potential, which is an important parameter for semiconductor electrodes. Actually, this determines the band edge positions at the semiconductor–electrolyte interface, thus fixing the energies of conduction band electrons and valence band holes reacting with the electrolyte solution. So, the shift of the OCV towards lower values is another indication of a better photocatalytic activity. The results in the inset of Fig. 4a indicate that both the TiO\(_2\) NPs and the TiO\(_2\) NTs samples have a lower flat band potential than the ZnO-based materials. Indeed, the TiO\(_2\) NTs and NPs samples almost present the same OCV (about 0.20 V RHE). Therefore, both the TiO\(_2\) nanostructures present the onset \(E^*\) at a lower value with respect to both the ZnO-based materials, as well as the coating of the ZnO NWs with the TiO\(_2\) anatase shell results in a higher photocatalytic performance compared to the bare ZnO NWs. In fact, the increased photocurrent density of the ZnO@TiO\(_2\) sample is reflected by both its higher STHE with respect to the ZnO NWs and the left-shift in the OCV, from 0.45 V RHE (for ZnO NWs) to 0.34 V RHE (for core–shell sample). The origin of this effect can depend on different reasons. First, well crystallized TiO\(_2\) nanoparticles on the TiO\(_2\) NPs, TiO\(_2\) NTs or deposited on the surface of the ZnO NWs (in the core–shell sample) could effectively diminish the surface recombination sites, thus increasing the recombination resistance between electrons in the photoanode and holes in the electrolyte, leading to longer charge life-time. On the other hand, electron transport within single crystalline ZnO NWs in the core–shell sample must be faster than in the pure NWs, due to a better charge separation induced by the formation of a heterojunction at the interface between the well crystallized ZnO and TiO\(_2\) materials, which was confirmed by TEM and diffuse reflectance analysis (explained above).

In order to investigate the photo-corrosion properties of the TiO\(_2\) and ZnO nanostructures, the stability of the photoanodes was investigated as a function of time. Fig. 4c shows the \(I–t\) curves of all samples working at \(-0.1\) V vs. Ag/AgCl (0.86 V RHE). This potential was chosen since it is a representative value after the photocurrent saturation for both the TiO\(_2\) nanostructures and is, as well, the potential of the maximum STHE for the ZnO NWs and ZnO@TiO\(_2\) samples. The maximum photocurrent densities reached at this potential for all the samples increase in the order: TiO\(_2\) NPs, TiO\(_2\) NTs, ZnO NWs and ZnO@TiO\(_2\), according to the following values: 0.016, 0.12, 0.14 and 0.19 mA cm\(^{-2}\), respectively, which are in agreement with the \(I\) values reported in the LSV (see Fig. 4a). The same trend was also found at higher potentials. Moreover, a good photo-current stability was observed for all the four samples under numerous light ON–OFF cycles over a time of 38 min. Additionally, TiO\(_2\) NTs and ZnO@TiO\(_2\) (the most performing samples) were subjected to long term \(I–t\) curves (12 h at 0.3 V vs. Ag/AgCl) under 1 sun AM1.5G illumination, after which they showed a reduction in the activity lower than 20% (see ESI, Fig. S1). Furthermore, the FESEM analysis performed after the PEC tests (see ESI, Fig. S2) did not show a significant photo-degradation of TiO\(_2\)-based nanostructures. This result suggests that at least a part of the decrease in the photocurrent, in such a long time chrono-amperometry measurement, under liquid bath conditions, could be due to mass-transport limitations caused by either O\(_2\) bubble formation or concentration gradients at the electrode surface, which can hinder the photo-activity of materials.

For more conclusive durability tests of the photoelectrodes, further tests should be subsequently made under continuous flow conditions in a different kind of electrochemical setup (see for instance the device reported in ref. 35). In contrast to the TiO\(_2\)-based electrodes, an initial stage of photo-corrosion was observed for the pristine ZnO NWs (see ESI, Fig. S2). This fact confirms the low photocorrosion resistance of the ZnO directly exposed to the NaOH electrolyte.

It is important to point out that for a feasible application of a water photo-electrolysis device, the anodic photo-electrodes should present: (i) a high UV-Vis light absorption, (ii) a reduced overpotential for the water oxidation reaction, and (iii) efficient charge transport properties to be able to sustain high photocurrent densities. If these conditions are satisfied, the photo-electrodes would be able to reach STHE values of 10–15% with the minimum applied bias. The best performing materials studied here, the TiO\(_2\) NTs and the ZnO@TiO\(_2\) core–shell samples, have different advantages and constraints that must be taken into consideration. With this aim, the relationship between the transport and the photo-catalytic properties of the studied nanostructures, and in particular of the TiO\(_2\) NTs and of the ZnO@TiO\(_2\) core–shell materials, is deeper investigated and discussed in the following sections.

3.4. Electrochemical impedance spectroscopy analysis

In order to better understand which is the most important process responsible for the different performances of the four
TiO₂ and ZnO investigated nanostructures, the PEC behavior of the studied photo-electrodes has been investigated using the EIS technique. The results of the EIS measurements performed at 1.23 V_RHE are reported in Fig. 5. In accordance with the LSV curves, the impedance modulus of both the TiO₂ photoelectrodes is larger than the ZnO-based ones (see Fig. 5a). Concerning the phase spectra, two features can be recognized, related to the two different processes occurring in the analyzed systems: a high frequency peak, associated with the charge transport properties of the photoelectrode material, and a low frequency peak associated with the charge transfer at the photoelectrode/electrolyte interface.¹⁴ For the TiO₂-based and pure ZnO NWs photoanodes the two processes partially overlap, thus resulting in the formation of a one broad peak; on the other hand, the core–shell sample exhibits two well-distinguished peaks, one centered at about 4 Hz and the other one at about 200 Hz. In order to evaluate the time constants associated with the different processes for all the analyzed samples, the EIS data were modeled through the equivalent circuit shown in Fig. 5b.¹⁴ composed of: a series resistance R_s (accounting for the resistances of the conductive substrate, of the external electrical contacts and of the liquid electrolyte), a parallel between the resistance R_H and the capacitance C_H at the Helmholtz double layer (related to the low frequency process), and a parallel between the resistance R_dl and the capacitance C_dl in the depletion layer in the semiconductor (related to the high frequency process). For all the samples, the computed curves match well with the experimental data, as is evident in Fig. 5. Starting from the fitting parameters, the time constants match well with the experimental data, as is evident in Fig. 5.

Table 1 Time constants related to the charge transfer processes involved in the water splitting reaction on the different TiO₂ and ZnO studied nanostructures, evaluated through EIS analysis at 1.23 V_RHE, under AM1.5G simulated sunlight (100 mW cm⁻²).

<table>
<thead>
<tr>
<th>Sample</th>
<th>Exposed surface area, SA (cm²)</th>
<th>R_s (Ω)</th>
<th>τ_H (s)</th>
<th>τ_dl (ms)</th>
</tr>
</thead>
<tbody>
<tr>
<td>TiO₂ NPs</td>
<td>1500</td>
<td>17.92</td>
<td>10.75</td>
<td>333</td>
</tr>
<tr>
<td>TiO₂ NTs</td>
<td>600</td>
<td>2.78</td>
<td>2.530</td>
<td>76.0</td>
</tr>
<tr>
<td>ZnO NWs</td>
<td>100</td>
<td>19.25</td>
<td>0.150</td>
<td>16.0</td>
</tr>
<tr>
<td>ZnO@TiO₂</td>
<td>110</td>
<td>19.09</td>
<td>0.130</td>
<td>3.00</td>
</tr>
</tbody>
</table>

Moreover, with the aim of evaluating the influence of the surface area on the photo-electrochemical properties of the materials, the exposed surface area (SA) of the nanostructures (calculated by considering the dimensions measured through FESEM images) is also reported in Table 1.

By looking at the calculated parameters, as expected, the R_s value obtained for the TiO₂ NT sample is one-order of magnitude lower than R_s obtained for the other samples, due to the higher conductivity of the Ti foil substrate with respect to the FTO film. Moreover, the TiO₂ NP film is characterized by slower processes, when compared to the other nanostructures. In particular, it exhibits time constants which are 4 times larger with respect to the NTs-based photoelectrode, although the TiO₂ NPs SA is about 2.5 times higher than the one of the NTs. Regarding the τ_dl values, this difference can be attributed to the faster electronic transport inside the 1D nanostructure, when compared to the charge transfer by hopping among the nanoparticles.¹⁶ Therefore, even if the photo-catalytic activity of the anatase crystalline phase found in both TiO₂-based materials should be similar (i.e. both these materials have a similar flat-band, as previously discussed), the transfer of charges at the TiO₂-electrolyte interphase is fastened due to the lower accumulation of charges in the NTs than in the NP nanostructure. As a consequence, the recombination of e⁻–h⁺ pairs is reduced, with a resulting increase in the kinetics of the water oxidation reaction in the NTs with respect to the NP sample, which is observed through the fastening of the charge-transfer at the semiconductor–electrolyte interphase (i.e. τ_H value). This hence explains the higher saturation photo-current evidenced with the TiO₂ NTs in comparison with the NP film (shown in Fig. 4a). In addition, as expected, the charge transport inside the ZnO NWs results even faster with respect to the polycrystalline TiO₂ NP and NT samples, the NWs being characterized by a monocrystalline structure.³⁷ Finally, the core–shell sample exhibited a five-times lower τ_dl value when compared to the bare nanowires. This feature can be explained by both the improvement in the electronic transport and in the efficient separation of charge-carriers at the ZnO@TiO₂ interphase¹⁸ induced by the

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![Fig. 5](image-url)  
**Fig. 5** (a) Bode plots of modulus (left axis) and phase (right axis) of the impedance of TiO₂ NPs, TiO₂ NTs, ZnO NWs and the ZnO@TiO₂ core–shell heterostructures acquired at an applied potential of 0.3 V_RHE (1.23 V_HH) under illumination. The points represent the experimental data while the solid lines are the fitting curves. (b) Equivalent circuit used to fit the EIS data.
The electronic properties vs. PEC behavior of TiO$_2$ NTs and ZnO@TiO$_2$ core–shells

Even if the core–shell material is characterized by better transport properties than the TiO$_2$ NTs, the latter demonstrated to achieve a STHE similar to the first one at a lower potential (see Section 3.3.). In order to analyze the reason for such a feature, the EIS measurements on these two materials were conducted in all the range of studied potentials, under sunlight illumination, and the results are reported in Fig. 6.

Both the materials evidenced almost constant charge transport parameters (i.e. $R_{dl}$ and $C_{dl}$) after 0.6 $V_{RHE}$, indicating a quasi-conductive behavior of both the semiconductors under the electric field induced by the applied bias potential. In all the range of studied potentials, it is moreover confirmed the faster electron transport (lower $\tau_{dl}$) within the ZnO@TiO$_2$ core–shells than in the TiO$_2$ NTs.

On the other hand, in contrast with the core–shell material in which both the charge transfer parameters $R_H$ and $C_H$ remain constant after 0.6 $V_{RHE}$ in the TiO$_2$ NTs the $R_H$ increases and the $C_H$ slightly decreases with the potential. Since the capacitance at the Helmholtz double layer is related to the reaction rate at the surface of the photo-catalyst under illumination, $C_H$ decreasing after 0.5 $V_{RHE}$ must be correlated with the achievement of the maximum STHE at such a potential for the TiO$_2$ NTs. In addition, the charge-transfer resistance ($R_H$) of the NTs increases with the potential, leading to a simultaneous increase of the charge-carrier recombination at the surface of the TiO$_2$ photo-catalyst, due to the reduction of the $e^{-}h^{+}$ separation efficiency. As a consequence of this and of the polycrystalline nature of the TiO$_2$ NTs, even if their exposed SA is six times higher than the one of the ZnO@TiO$_2$ sample, the $\tau_H$ (which is correlated with the reaction kinetics) remains 10-fold larger in the NTs than in the core–shells for all the range of applied potentials.

These findings evidence that not always the benefits of material nanostructuration could outweigh the disadvantages. The advantages are the high surface area and absorption volume close to the semiconductor–electrolyte interface, allowing the effective collection and reaction of photo-generated holes. The disadvantages are the partial loss of the electric field for charge separation and the increased opportunity for electrons to recombine with species at the electrode surface or in the electrolyte before being collected at the conductive substrate. For such a reason, the other two major factors that can affect photocurrent efficiency of the nanostructured electrodes must be properly tuned: (i) the band gap energy, and (ii) the density of surface states and defects.

Regarding the first factor, the TiO$_2$ NTs have a slightly higher band gap (3.27 eV) than the ZnO@TiO$_2$ sample (3.25 eV), and thus the core–shell ability to exploit the visible component of sunlight illumination is slightly better than for the NTs. However, when these materials are illuminated in the UV-Vis range with the doubled of the intensity previously used (about 220 mW cm$^{-2}$), the $J$ value at 1.23 $V_{RHE}$ is increased 5 times with the NTs and only 2.4 times with the core–shells (as observed by comparing Fig. 4a and 7a). In addition, it is interesting to notice that under such conditions the maximum STHE are proportionally enhanced in both the materials, but with a different factor: 2.4 times for the NTs and only 1.2 times for the core–shell. These results could be justified by the higher IPCE of the NTs under UV illumination (maximum of 85%) than for the core–shell sample (maximum of 50%) at 1.23 $V_{RHE}$ (data not shown): in fact, in the tests reported in Fig. 7a the UV component is about 4 times larger than in the previous ones (Fig. 4a). Moreover, these results are in agreement with the recent work of Qorbani et al., in which TiO$_2$ NTs were tested with different intensities of simulated sunlight up to 600 mW cm$^{-2}$ and yielded a linear dependency between the generated photocurrent density and the applied illumination intensity, suggesting that the charge-carrier ($e^{-}h^{+}$) generation rate is the limiting step for the PEC water splitting.
Regarding the second factor, the charge carrier density was calculated according to the Mott–Schottky equation,\(^{(5)}\) in order to evaluate the surface properties of these two nanostructures:

\[
\frac{1}{C_{SC}^2} = \frac{2}{e \cdot e_0 \cdot N_d} \left( E - E_{FB} - \frac{kT}{e} \right)
\]

where \(C_{SC}\) is the capacitance of the space charge region, \(e_0\) is the permittivity of the free space, \(e\) is the dielectric constant of the semiconductor (100 for TiO\(_2\) and 19 for the core–shell sample, calculated as a weighted volume value between \(e\) of both ZnO and TiO\(_2\)), \(N_d\) is the donor density, \(e\) is the electron charge value, \(E\) is the applied potential, \(E_{FB}\) is the flat band potential and \(kT/e\) is the temperature dependent correction term (25 mV at room temperature).

The \(N_d\) values obtained from the linear fitting process are \(7.05 \times 10^{19}\) cm\(^{-3}\) for the TiO\(_2\) NTs and \(5.71 \times 10^{19}\) cm\(^{-3}\) for the core–shells (see Fig. 7b), which are comparable with those usually observed for ZnO NWs and TiO\(_2\) NTs.\(^{23,41}\) The materials have similar \(N_d\); however, if these values are normalized by the SA, it results that the core–shells \((5.19 \times 10^{19})\) have a higher donor density per unit of active surface with respect to the TiO\(_2\) NTs \((1.18 \times 10^{16})\). A higher \(N_d\) can also shift the Fermi level of semiconductors toward its conduction band, which further facilitates the charge separation at the semiconductor/electrolyte interface. Thus, this enhanced charge separation and the most favorable charge transport are the most probable reasons for the higher photocurrent values reached with the core–shell samples at high potentials (>0.9 V vs RHE) than the ones obtained with the pure TiO\(_2\) nanostructure with the saturation of the photo-current.

These results, together with the ones reported in the Sections 3.3. and 3.4., evidence the promising photo-electrochemical ability of both the TiO\(_2\) NTs and ZnO@TiO\(_2\) core–shell nanostructures. In addition, they indicate that different possible strategies for optimizing the solar-induced water splitting activity of these nanostructured photoelectrodes can be suggested. In particular:

- The main advantage of the TiO\(_2\) NTs is the low flat-band potential, which allows obtaining high photo-currents with a reduced bias. This intrinsic property of the TiO\(_2\) NTs contributes in obtaining high STHE with a low consumption of extra energy in the PEC water splitting system. The deposition of a co-catalyst could be for example a key solution to improve the charge-carrier separation at the TiO\(_2\) NTs-electrolyte interphase, which has been identified from our results to be the factor limiting their photocurrent. For example, the deposition of Pt nanoparticles in the top and walls of 10 µm-long TiO\(_2\) nanotube arrays made by Lai et al.\(^{(42)}\) yielded an enhancement of \(J\) from 16.3 to 24.2 mA cm\(^{-2}\) in 2 M Na\(_2\)CO\(_3\)–ethylene glycol solution with 320 mW cm\(^{-2}\) of simulated sunlight illumination. However, there are a few examples in which low-cost and earth-abundant catalysts \(\text{(e.g., Co, Mn- or Cu-based materials)}\) have been deposited on TiO\(_2\) NTs.\(^{(43)}\) Similarly, the deposition of a co-catalyst in the high available surface of the TiO\(_2\) in the shell of the ZnO@TiO\(_2\) electrode can be exploited to reduce its onset potential.

- Both the TiO\(_2\) NTs and the core–shells can be prepared having different sizes and lengths with a low-cost process and in a few synthesis steps. However, there are a few examples in the literature of ZnO@TiO\(_2\) electrodes prepared and tested for the PEC water oxidation\(^{(18,44)}\) and the ZnO NW length is often <2 µm. In contrast, the anodic oxidation process commonly used for the synthesis of the NTs renders easy the increase in their length and, thus, the enhancement of the active surface available for the reaction. It is important to point out that the results here reported with the ZnO@TiO\(_2\) \((J < 0.7 \text{ mA cm}^{-2})\) are in-line with or even more performing than some literature values obtained for both pure and doped ZnO NWs\(^{(45)}\) and for 1D TiO\(_2\)–ZnO nanostructures tested under AM1.5G sunlight. Even though, good performances have also been reached with other TiO\(_2\)-based nanostructures: e.g. Pan et al. reported 2 mA cm\(^{-2}\) obtained with a 2–4 µm-long hierarchical TiO\(_2\) nanobelts–ZnO nanorod in 0.5 M Na\(_2\)SO\(_4\) (120 mW cm\(^{-2}\)) and Wang et al.\(^{(31)}\) obtained ~2.8 mA cm\(^{-2}\) with H\(_2\)-treated rutile TiO\(_2\) NWs (2–3 µm length). The latter was the most performing value reached with TiO\(_2\) NWs. Instead, TiO\(_2\) nanotube arrays with a length ranging from hundreds of nm up to 45 µm, with different aspect-ratios, were reported with even better results for the water photo-electrolysis.\(^{(46–48)}\) For instance, Sun et al.\(^{(46)}\) reached 5 mA cm\(^{-2}\) in KOH (110 mW cm\(^{-2}\)) with TiO\(_2\) NTs with
an optimized length of 7 µm, made in 1 h of electrochemical anodization; Gong et al.\textsuperscript{47} prepared highly ordered TiO\textsubscript{2} nanotube arrays by a three-step electrochemical anodization process with a length up to 18 µm (i.d. 50 nm), and reached a maximum \( J \) of about 24 mA cm\(^{-2}\) with the 1.2 µm-long sample in 0.5 M KOH.

- The photo-catalytic properties of both the TiO\textsubscript{2} NTs and the ZnO@TiO\textsubscript{2} can be further enhanced by modifying their optical or surface properties.\textsuperscript{49} In this regard, one approach that has been often used is the doping (e.g. with C, N, S etc.) or the creation of bilayered systems with low band-gap semiconductors (e.g. WO\textsubscript{3}, CdSe, CdS, etc.\textsuperscript{49,50}) in order to enhance visible light absorption, charge separation and charge transport. Good examples are the C-doped TiO\textsubscript{2} NTs prepared by Park et al.\textsuperscript{51} (\( \sim 2 \) µm length, i.d. 70 nm) obtaining a \( J \) value close to 1 mA cm\(^{-2}\), or the TiO\textsubscript{2}–C\textsubscript{2} nanotubes annealed in a H\textsubscript{2} atmosphere by Mohapatra et al.\textsuperscript{52} reaching about 3 mA cm\(^{-2}\), both under sunlight conditions in a 1 M KOH electrolyte. Nonetheless, really impressive results were recently reported by combining the use of heterostructures with a high visible light absorber and concentrator. For instance, Qorbani et al.\textsuperscript{40} made CdS-sensitized TiO\textsubscript{2} NTs (2.9 µm length, 125 nm i.d.) yielding up to 28 mA cm\(^{-2}\) with an illumination of 4 suns (400 mW cm\(^{-2}\)), and Li et al.\textsuperscript{53} prepared ZnO/CuS and ZnO/CulInS\textsubscript{2} core/shell nanorod arrays producing about 8 and 16.9 mA cm\(^{-2}\), respectively, by using 5 suns of incident light and the Na\textsubscript{2}S electrolyte.

- As shown in Fig. 7a and as discussed above, the illumination with concentrated light is an operative condition that could really mark the difference for the performance of a TiO\textsubscript{2} or ZnO-based device, due not only to the high amount of photo-generated holes that can enhance the inherent activity of these materials, but also to the low-cost availability of solutions to produce concentrated light (i.e. through the use of a polymeric Fresnel lens).

4. Conclusions

Four TiO\textsubscript{2} and ZnO-based nanostructures, having the same active area and similar thicknesses, were deeply characterized and compared in terms of their structural and photo-electrochemical properties. FESEM and TEM analysis evidenced the structural differences and the high degree of crystallinity of the various materials. Optical measurements allowed us to evaluate the energy gap values and to appreciate the occurrence of scattering effects due to the high surface area of the different structures coupled with their characteristic dimensions. Photo-electrochemical activity measurements and electrochemical impedance spectroscopy analysis showed an improvement in charge collection efficiency of 1D-nanostructures, related to a more efficient electron transport in the materials. The highest photocurrent density and photo-conversion efficiency in our system were obtained with the ZnO@TiO\textsubscript{2} core–shells and with the TiO\textsubscript{2} NTs. The core–shell heterostructure reached up to 0.63 mA cm\(^{-2}\) at 1.7 \( V_{\text{RHE}} \) and had a maximum STHE of 0.073% (at 0.9 \( V_{\text{RHE}} \)) under sunlight illumination of AM1.5G (100 mW cm\(^{-2}\)), this being the best performance ever reported for ZnO@TiO\textsubscript{2} for this application. In addition, the TiO\textsubscript{2} NTs attained a saturation photocurrent of 0.12 mA cm\(^{-2}\) from about 0.5 \( V_{\text{RHE}} \), potential at which a maximum STHE of 0.071% yielded, similar to what obtained with the core–shell sample under the same operative conditions but at a lower applied bias. EIS analysis evidenced that the TiO\textsubscript{2} NPs exhibited time constants 4 times higher with respect to the NTs-based photo-electrode, which justifies the worst performance of the 3D NP nanostructure with respect to the 1D TiO\textsubscript{2} NTs. Moreover, the increase of the charge-carrier recombination at the TiO\textsubscript{2}–electrolyte interface in the TiO\textsubscript{2} NTs with the applied potential indicated a reduction of the \( e^-\text{–h}^+ \) separation efficiency in this polycrystalline material, explaining the reason for the photocurrent saturation. Therefore, the charge transfer time constant obtained for the TiO\textsubscript{2} NTs was 10-fold higher than in the core–shells, for all the range of applied potentials: this occurrence was identified to be mainly responsible for the lower photocurrents of the TiO\textsubscript{2} NTs with respect to the core–shell material at high bias. In contrast, the enhanced performance of the core–shell samples was attributed to the high electron mobility within the monocristalline 1D ZnO nanostructure (i.e. a five-times lower \( \tau_{\text{el}} \) value when compared to the bare nanowires due to the efficient separation of charge-carriers at the ZnO@TiO\textsubscript{2} interphase) coupled to the high specific surface area of the TiO\textsubscript{2} polycrystalline shell, which increases the charge-transport about 13% and thus the kinetics for the water photo-electrolysis in this material with respect to the bare ZnO NWs. In conclusion, the efficient application of both the TiO\textsubscript{2} NTs and the ZnO@TiO\textsubscript{2} core–shell photoanodes opens up important perspectives, not only in the water splitting application field, but also for other photo-catalytic applications (e.g. photovoltaic cells, degradation of organic substances), due to their chemical stability, easiness of preparation and improved transport properties. Different optimization strategies (i.e. co-catalysis, surface modifications to adsorb visible light, increase of thickness, use of concentrated solar light) were identified for each of the studied materials in order to increase their effectiveness and to achieve the efficiency values required for commercial applications.

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Notes and references
